# Product Preview

# Low-Voltage CMOS Octal Transceiver With 5V-Tolerant Inputs and Outr

# With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX2245 is a high performance, non-inverting octal transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V<sub>I</sub> specification of 5.5V allows MC74LCX2245 inputs to be safely driven from 5V devices. The MC74LCX2245 is designed to reduce output overshoot and undershoot and is suitable for memory address driving and all TTL level bus oriented transceiver applications; especially those requiring the very quiet outputs.

Current drive capability is 12mA at both A and B ports. The Transmit/Receive (T/R) input determines the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V VCC Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 12mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

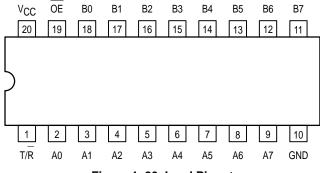


Figure 1. 20-Lead Pinout (Top View)

## MC74LCX2245



LOW-VOLTAGE CMOS OCTAL TRANSCEIVER



#### **DW SUFFIX** 20-LEAD PLASTIC SOIC CASE 751D-04



#### M SUFFIX 20-LEAD PLASTIC SOIC EIAJ CASE 967-01



SD SUFFIX 20-LEADPLASTIC SSOP CASE 940C-03



**DT SUFFIX** 20-LEAD PLASTIC TSSOP CASE 948E-02

#### **PIN NAMES**

Pins	Function
OE	Output Enable Input
T/R	Transmit/Receive Input
A0-A7	Side A 3–State Inputs or 3–State
	Outputs
B0-B7	Side B 3–State Inputs or 3–State
	Outputs

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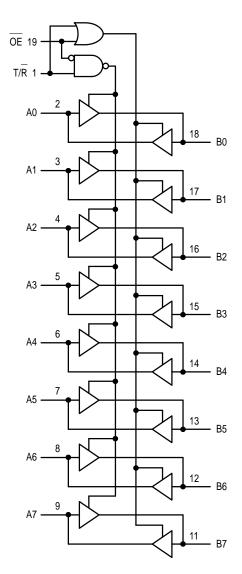


Figure 2. Logic Diagram

INP	UTS	OPERATING MODE		
OE	T/R	Non-Inverting		
L	L	B Data to A Bus		
L	Н	A Data to B Bus		
Н	X	Z		

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; For ICC reasons, Do Not Float Inputs

#### **ABSOLUTE MAXIMUM RATINGS\***

Symbol	Parameter	Value	Condition	Unit
Vcc	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 ≤ V <sub>I</sub> ≤ +7.0		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3-State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
ΙΙΚ	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
lok	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	VO > VCC	mA
IO	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100	_	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	_	°C

<sup>\*</sup> Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3–State)	0 0		V <sub>CC</sub> 5.5	V
IOH	HIGH Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			-12	mA
loL	LOW Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			12	mA
ЮН	HIGH Level Output Current, V <sub>CC</sub> = 2.7V - 3.0V			-8	mA
loL	LOW Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			8	mA
TA	Operating Free-Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8V to 2.0V, $V_{CC} = 3.0V$	0		10	ns/V

#### DC ELECTRICAL CHARACTERISTICS

			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Characteristic	Condition	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V	2.0		V
V <sub>IL</sub>	LOW Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$ ; $I_{OH} = -100\mu A$	V <sub>CC</sub> - 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -4mA$	2.2		
		$V_{CC} = 2.7V; I_{OH} = -8mA$	2.0		
		$V_{CC} = 3.0V; I_{OH} = -6mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -12mA$	2.0		

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<sup>1.</sup> Output in HIGH or LOW State. IO absolute maximum rating must be observed.

<sup>2.</sup> These values of V<sub>I</sub> are used to test DC electrical characteristics only.

### DC ELECTRICAL CHARACTERISTICS (continued)

			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Characteristic	Condition	Min	Max	Unit
V <sub>OL</sub>	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$ ; $I_{OL} = 100\mu A$		0.2	V
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 4mA		0.4	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 8mA		0.6	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 6mA		0.55	
		$V_{CC} = 3.0V; I_{OL} = 12mA$		0.8	
Ц	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3–State Output Current	$2.7 \le V_{CC} \le 3.6V$ ; $0V \le V_{O} \le 5.5V$ ; $V_{I} = V_{IH}$ or $V_{IL}$		±5.0	μΑ
loff	Power-Off Leakage Current	$V_{CC} = 0V$ ; $V_I$ or $V_O = 5.5V$		10	μΑ
ICC	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$ ; $V_I = GND$ or $V_{CC}$		10	μΑ
		$2.7 \le V_{CC} \le 3.6V$ ; $3.6 \le V_I$ or $V_O \le 5.5V$		±10	μΑ
ΔlCC	Increase in I <sub>CC</sub> per Input	$2.7 \le V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$		500	μΑ

#### AC CHARACTERISTICS (Note 3., $t_R = t_F = 2.5$ ns; $C_L = 50$ pF; $R_L = 500\Omega$ )

				Limits		
			T <sub>A</sub> = -40°C to +85°C			
			V <sub>CC</sub> = 3.0	V to 3.6V	V <sub>CC</sub> = 2.7V	]
Symbol	Parameter	Waveform	Min	Max	Max	Unit
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay Input to Output	1	1.5 1.5	10.0 10.0	11.0 11.0	ns
<sup>t</sup> PZH <sup>t</sup> PZL	Output Enable Time to High and Low Level	2	1.5 1.5	11.5 11.5	12.5 12.5	ns
<sup>t</sup> PHZ <sup>t</sup> PLZ	Output Disable Time From High and Low Level	2	1.5 1.5	7.5 7.5	8.5 8.5	ns
tOSHL tOSLH	Output-to-Output Skew (Note 4.)			1.0 1.0		ns

<sup>3.</sup> These AC parameters are preliminary and may be modified prior to release.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

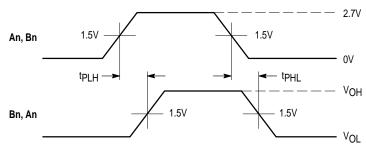
			T <sub>A</sub> = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V <sub>OLP</sub>	Dynamic LOW Peak Voltage (Note 5.)	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V
VOLV	Dynamic LOW Valley Voltage (Note 5.)	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V

<sup>5.</sup> Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

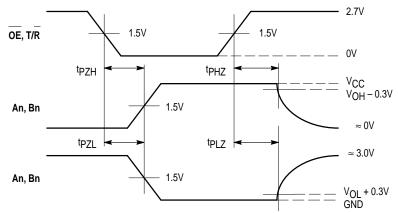
#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Parameter Condition		Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	25	pF



#### WAVEFORM 1 - PROPAGATION DELAYS

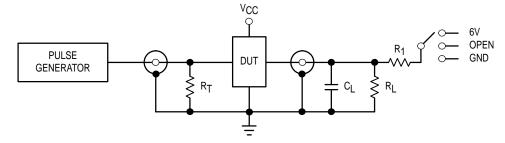
 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz;  $t_W = 500$ ns



#### WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

 $t_R$  =  $t_F$  = 2.5ns, 10% to 90%; f = 1MHz;  $t_W$  = 500ns

Figure 3. AC Waveforms



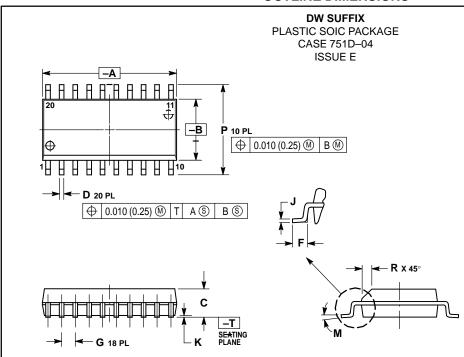
TEST	SWITCH
<sup>t</sup> PLH <sup>, t</sup> PHL	Open
tPZL, tPLZ	6V
Open Collector/Drain tpLH and tpHL	6V
tPZH, tPHZ	GND

 $C_L$  = 50pF or equivalent (Includes jig and probe capacitance)  $R_L$  =  $R_1$  = 500 $\Omega$  or equivalent  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

Figure 4. Test Circuit

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#### **OUTLINE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
  - ANSI Y14.5M, 1982.
    2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
   MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.
- (0.005) FER SIDE.

  5. DIMENSION D DOES NOT INCLUDE

  DAMBAR PROTRUSION. ALLOWABLE

  DAMBAR PROTRUSION SHALL BE 0.13

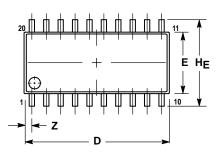
  (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

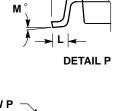
	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	12.65	12.95	0.499	0.510
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050	BSC
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

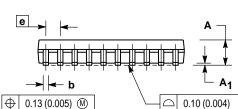
#### **M SUFFIX**

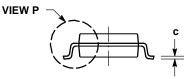
PLASTIC SOIC EIAJ PACKAGE CASE 967-01 ISSUE O

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#### NOTES:

 $Q_1$ 

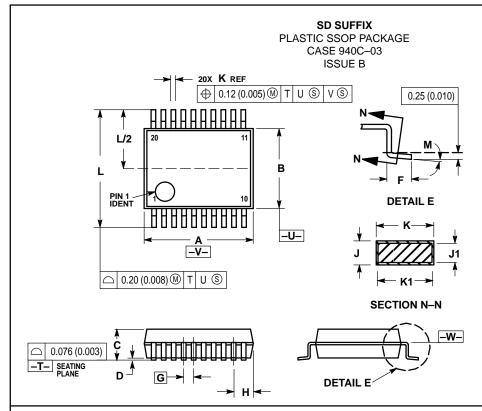
- 1 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982.

  2 CONTROLLING DIMENSION: MILLIMETER.

  3 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- PER SIDE.
  TERMINAL NUMBERS ARE SHOWN FOR
  REFERENCE ONLY.
  THE LEAD WIDTH DIMENSION (b) DOES NOT
  INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) DANIORAR FRO I RUSION SHALL BE 0.08 (0.003)
  TOTAL IN EXCESS OF THE LEAD WIDTH
  DIMENSION AT MAXIMUM MATERIAL CONDITION.
  DAMBAR CANNOT BE LOCATED ON THE LOWER
  RADIUS OR THE FOOT. MINIMUM SPACE
  BETWEEN PROTRUSIONS AND ADJACENT LEAD
  TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
E	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050	) BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
$Q_1$	0.70	0.90	0.028	0.035
Z		0.81		0.032

#### **OUTLINE DIMENSIONS**



- NOTES:
  13 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  14 CONTROLLING DIMENSION: MILLIMETER.
- 14 CONTROCLING DIMENSION, MILLIUMETER.
  15 DIMENSION A DOES NOT INCLUDE MOLD FLASH,
  PROTRUSIONS OR GATE BURRS. MOLD FLASH
  OR GATE BURRS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE.

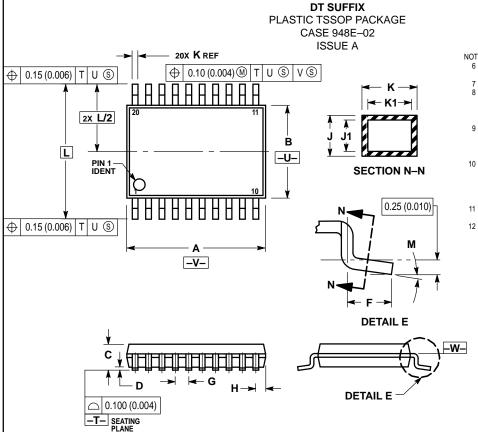
  16 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  17 DIMENSION K DOES NOT INCLUDE DAMBAR
- PROTRUSION/INTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF K DIMENSION AT MAXIMUM MATERIAL CONDITION DAMBAR INTRUSION SHALL NOT REDUCE DIMENSION K BY MORE THAN 0.07 (0.002) AT LEAST MATERIAL
  CONDITION.

  18 TERMINAL NUMBERS ARE SHOWN FOR
  REFERENCE ONLY.

  19 DIMENSION A AND B ARE TO BE DETERMINED
  AT DATUM PLANE—W—.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	7.07	7.33	0.278	0.288
В	5.20	5.38	0.205	0.212
С	1.73	1.99	0.068	0.078
D	0.05	0.21	0.002	0.008
F	0.63	0.95	0.024	0.037
G	0.65 BSC		0.026 BSC	
Н	0.59	0.75	0.023	0.030
J	0.09	0.20	0.003	0.008
J1	0.09	0.16	0.003	0.006
K	0.25	0.38	0.010	0.015
K1	0.25	0.33	0.010	0.013
Ĺ	7.65	7.90	0.301	0.311
M	0 °	8 °	0 °	8 °



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- 6 DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1982.
  7 CONTROLLING DIMENSION: MILLIMETER.
  8 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD
   FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 10 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

  11 TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

  12 DIMENSION A AND B ARE TO BE DETERMINED
- AT DATUM PLANE -W-

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С		1.20	_	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

#### MC74LCX2245

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